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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# 2SK2554

## Silicon N Channel MOS FET

REJ03G1016-0600

(Previous: ADE-208-359D)

Rev.6.00 Sep 07, 2005

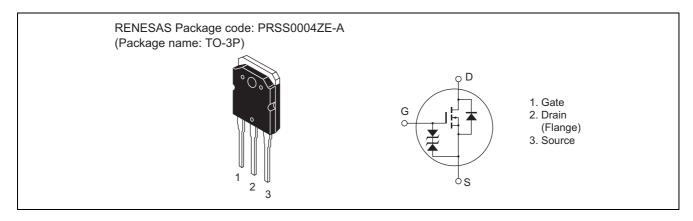
### **Application**

High speed power switching

#### **Features**

- Low on-resistance
- $R_{DS(on)} = 4.5 \text{ m}\Omega \text{ typ.}$
- High speed switching
- 4 V gate drive device can be driven from 5 V source

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	75	A
Drain peak current	I <sub>D(pulse)</sub> *1	300	A
Body to drain diode reverse drain current	I <sub>DR</sub> * <sup>2</sup>	75	A
Avalanche current	I <sub>AP</sub> *3	50	A
Avalanche energy	E <sub>AR</sub> *3	214	mJ
Channel dissipation	Pch*2	150	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

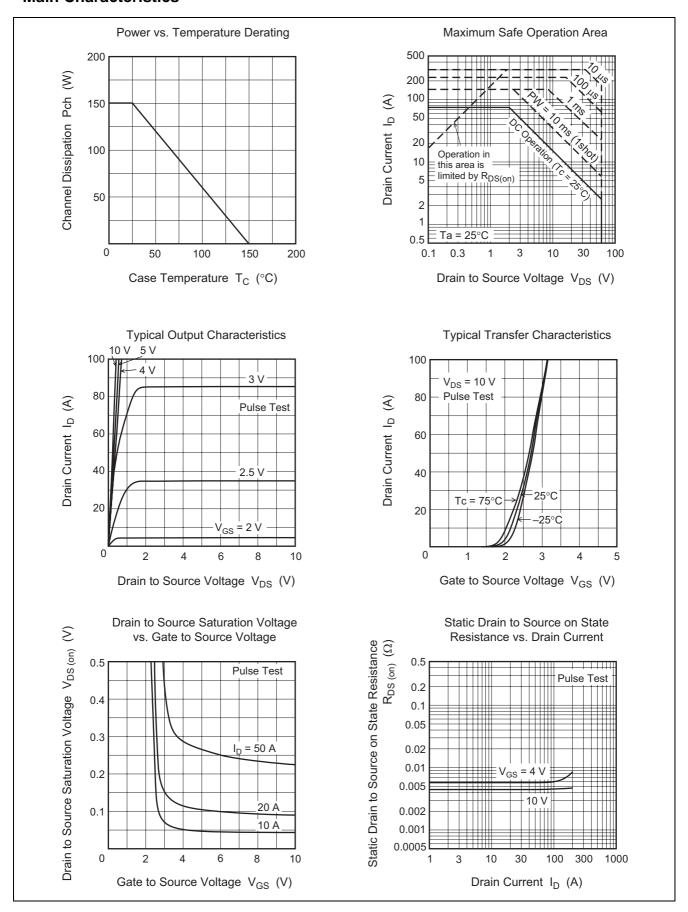
### **Electrical Characteristics**

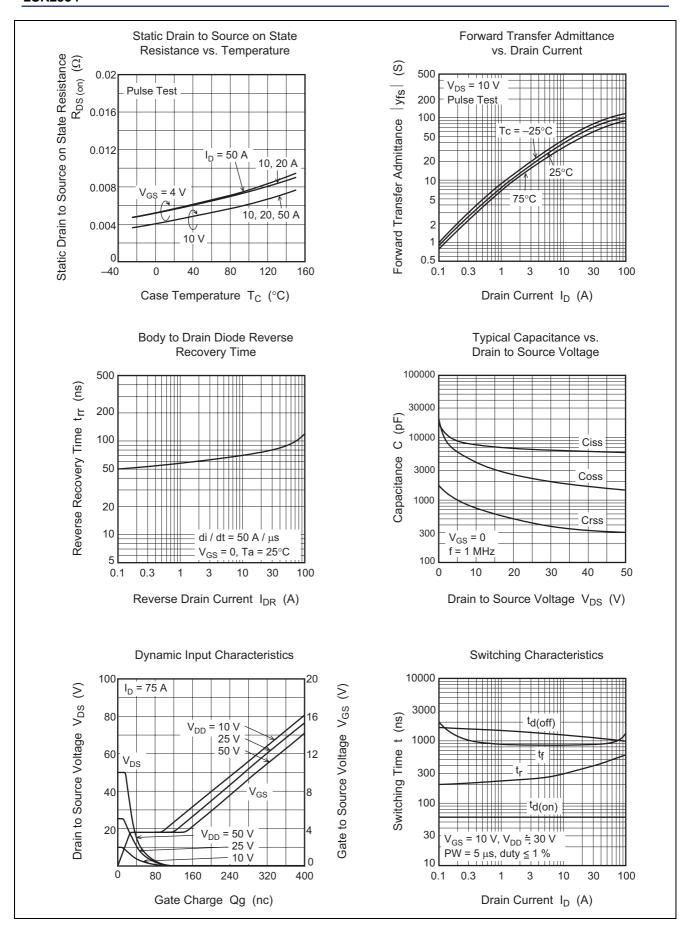
 $(Ta = 25^{\circ}C)$ 

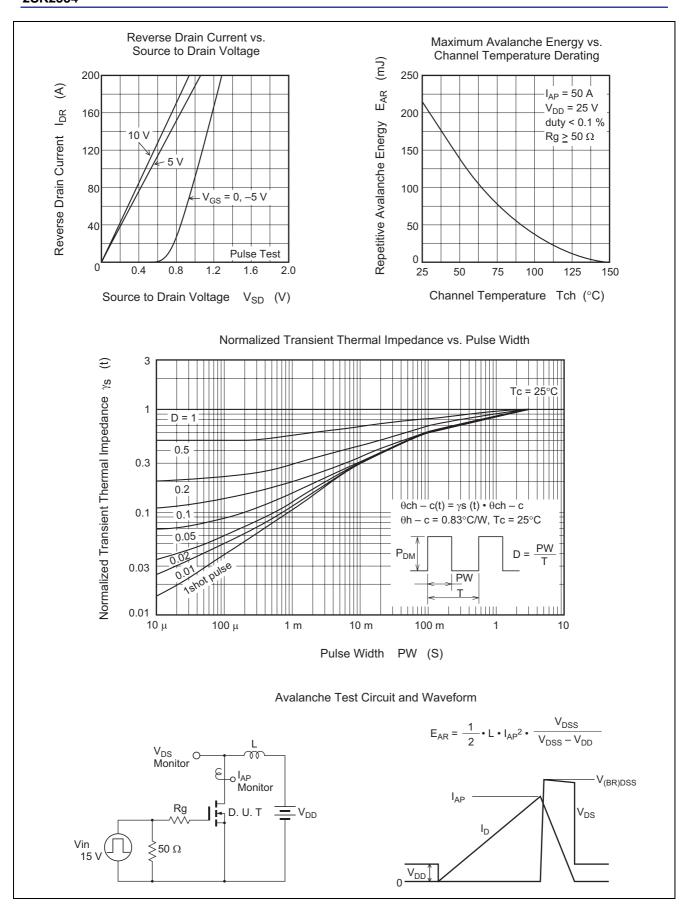
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	100	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R <sub>DS(on)</sub>	_	4.5	6	mΩ	$I_D = 40 \text{ A}, V_{GS} = 10 \text{ V}^{*4}$
resistance		_	5.8	10	mΩ	$I_D = 40 \text{ A}, V_{GS} = 4 \text{ V}^{*4}$
Forward transfer admittance	y <sub>fs</sub>	50	80	_	S	$I_D = 40 \text{ A}, V_{DS} = 10 \text{ V}^{*4}$
Input capacitance	Ciss	_	7700	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	4100	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	760	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	60	_	ns	$I_D = 40 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time	t <sub>r</sub>	_	420	_	ns	$R_L = 0.75 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	1200	_	ns	
Fall time	t <sub>f</sub>	_	900	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	0.95	_	V	$I_F = 75 \text{ A}, V_{GS} = 0$
Body to drain diode reverse	t <sub>rr</sub>	_	105	_	ns	$I_F = 75 \text{ A}, V_{GS} = 0$
recovery time						$di_F / dt = 50 A / \mu s$

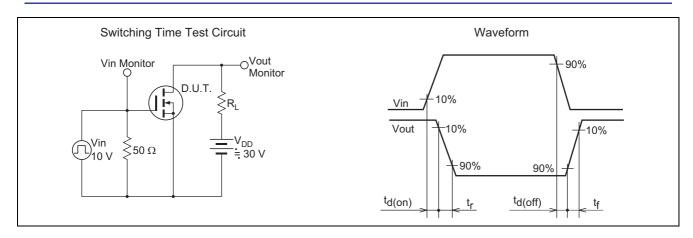
Note: 4. Pulse Test

#### **Main Characteristics**

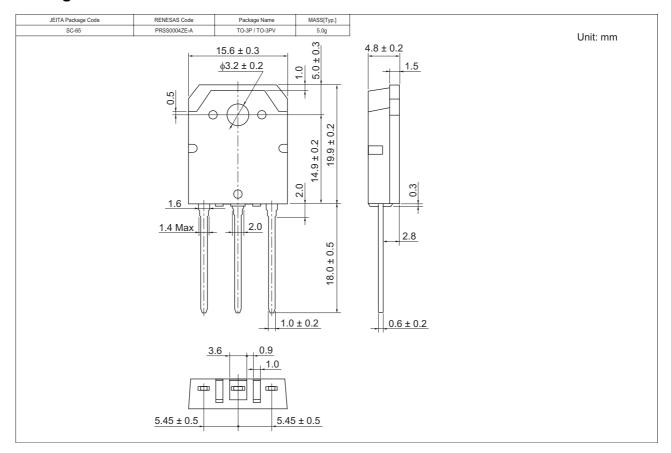








### **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SK2554-E	30 pcs	Plastic magazine

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